N-Channel 30-V (D-S) MOSFET

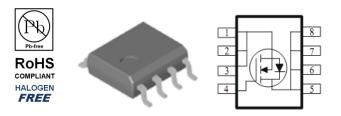
Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- Fast switching speed

Typical Applications:

- DC/DC Conversion
- Power Routing
- Motor Drives

PRODUCT SUMMARY				
Vds (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)		
30	3 @ V _{GS} = 10V	27		
	4.2 @ V _{GS} = 4.5V	23		



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage	V _{GS}	±20	v		
Continuous Drain Current ^a	T _A =25°C	1	27		
	T _A =70°C	I _D	22.2	А	
Pulsed Drain Current ^b	I _{DM}	100			
Continuous Source Current (Diode Conduction) ^a		I _S	5	А	
Dower Dissinction ^a	T _A =25°C	P _D	3.1	W	
Power Dissipation ^a	T _A =70°C	'D	2.2	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	R _{eja}	40	°C/W	
	Steady State	INθJA	80		

Notes

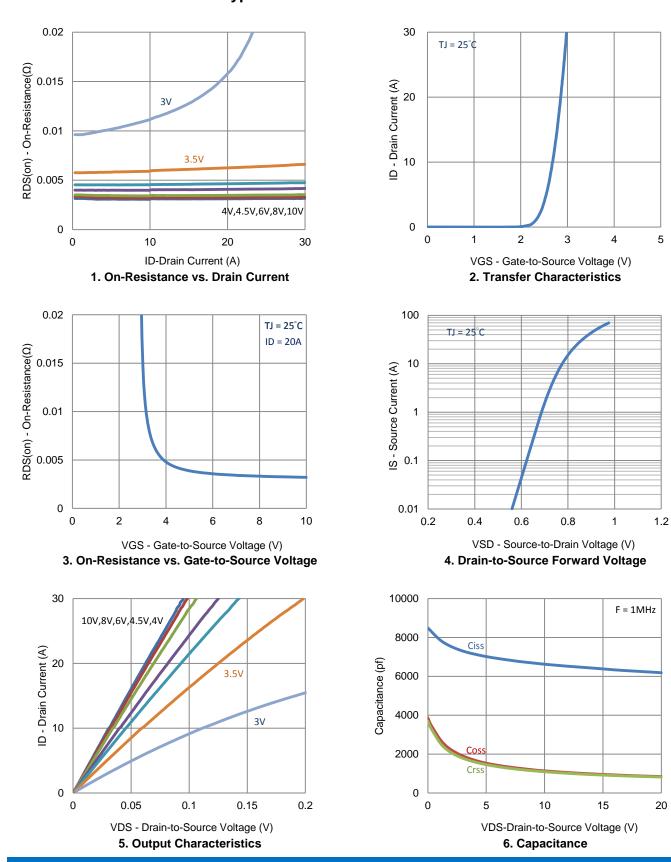
- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1 uA		
	IDSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	50			Α	
Drain Course On Desistance a	r	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$			3	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 16 \text{ A}$			4.2	11122	
Forward Transconductance ^a	g _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		15		S	
Diode Forward Voltage ^a	V_{SD}	$I_{S} = 2.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.73		V	
	Dynamic ^b						
Total Gate Charge	Qg			59			
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 20 \text{ A}$		18		nC	
Gate-Drain Charge	Q_{gd}	$I_D = 20$ A		25		1	
Turn-On Delay Time	t _{d(on)}			19			
Rise Time	t _r	$V_{DS} = 15 \text{ V}, \text{ R}_{L} = 0.8 \Omega,$ $I_{D} = 20 \text{ A},$		30		-	
Turn-Off Delay Time	t _{d(off)}	$V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{GEN}} = 6 \Omega$		161		ns	
Fall Time	t _f	$v_{\text{GEN}} = 10$ $v_{\text{, }}$ $r_{\text{GEN}} = 0.22$		59			
Input Capacitance	C _{iss}			6380			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		952		pF	
Reverse Transfer Capacitance	C _{rss}			919			

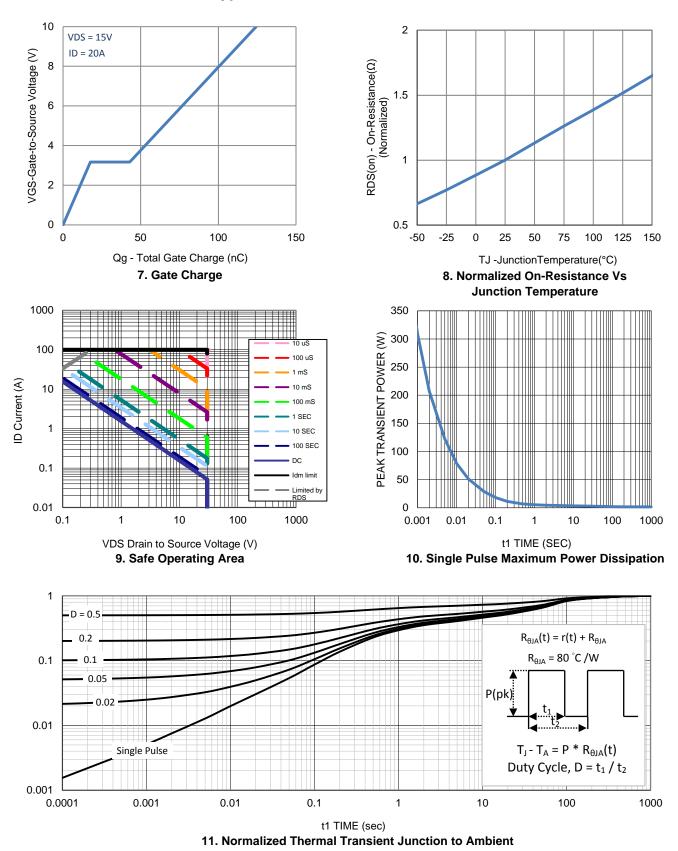
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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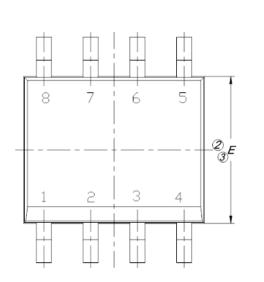
Typical Electrical Characteristics

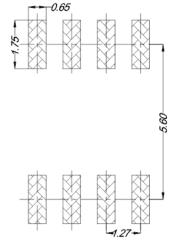


Typical Electrical Characteristics

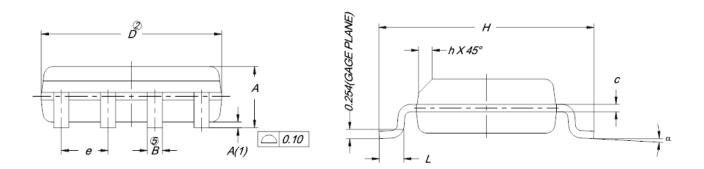
Package Information

Land Pattern (Only for Reference)





5.1.4	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
А	1.35	1.55	1.75		
A(1)	0.10	0.18	0.25		
В	0.38	0.45	0.51		
С	0.19	0.22	0.25		
D	4.80	4.90	5.00		
E	3.80	3.90	4.00		
е	1.27 BSC				
н	5.80	6.00	6.20		
L	0.50	0.72	0.93		
α	0°	4°	8°		
h	0.25	0.38	0.50		



Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- Dimension "B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of "B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.